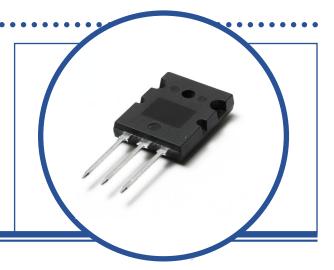
## SILICON EPITAXIAL PLANAR PNP TRANSISTOR



### MAG9412

- TO-264 Plastic Package
- Complimentary PNP MAG6332
- Designed specifically for audio power amplifier applications
- Highest current audio bipolar available on the market with widest safe operating area



### **ABSOLUTE MAXIMUM RATINGS** (T<sub>A</sub> = 25°C unless otherwise stated)

V <sub>CBO</sub>	Collector – Base Voltage	-230V
$V_{CEO}$	Collector – Emitter Voltage	-230V
$V_{EBO}$	Emitter – Base Voltage	-5V
IC	Continuous Collector Current	-30A
$I_{B}$	Base Current	-8A
ICM	Peak Collector Current	-45A
$P_{D}$	Total Power Dissipation at $T_A = 25^{\circ}C$	400W
TJ	Maximum Junction Temperature	150°C
$T_{stg}$	Storage Temperature Range	-55 to +150°C

#### THERMAL PROPERTIES

Symbols	Parameters	Min.	Тур.	Мах.	Units
R <b>e</b> JC	Thermal Resistance, Junction To Case			0.32	°C/W



# SILICON EPITAXIAL PNP TRANSISTOR MAG9412



### **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise stated)

Symbols	Parameters	Test Conditions		Min.	Тур	Max.	Units
I <sub>СВО</sub>	Collector-Cut-Off Current	V <sub>CB</sub> = 230V				-100	μA
I <sub>EBO</sub>	Emitter-Cut-Off-Current	V <sub>EB</sub> = 5V				-100	μΑ
V(BR)CEO	Collector-Base Breakdown Voltage	I <sub>C</sub> = 10mA		-230			V
VCE(sat) <sup>(1)</sup>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 10A	$I_B = 1A$			-1	
vCE(sat)		I <sub>C</sub> = 20A	$I_B = 2A$			-1.5	V
V <sub>BE(sat)</sub> <sup>(1)</sup>	Base-Emitter Saturation Voltage	I <sub>C</sub> = 20A	I <sub>B</sub> = 2A			-2.0	
h <sub>FF</sub> <sup>(1)</sup>	Forward-current transfer	I <sub>C</sub> = 5A	$V_{CE} = 4V$	50 <sup>(2)</sup>			
	ratio	I <sub>C</sub> = 10A	V <sub>CE</sub> = 4V	45			

#### **DYNAMIC CHARACTERISTICS**

f <sub>T</sub>	Transition Frequency	I <sub>E</sub> = 2A	V <sub>CE</sub> = 12V		60	MHz
C <sub>obo</sub>	Output Capacitance	$V_{CB} = 10V$		800	900	F
		f = 1.0MHz			p⊦	

#### Notes

(1) Pulse Width  $\leq$  300us,  $\delta \leq$  2%

(2) h<sub>FE</sub> Rank : A (50 to 100), B(70 to 140)

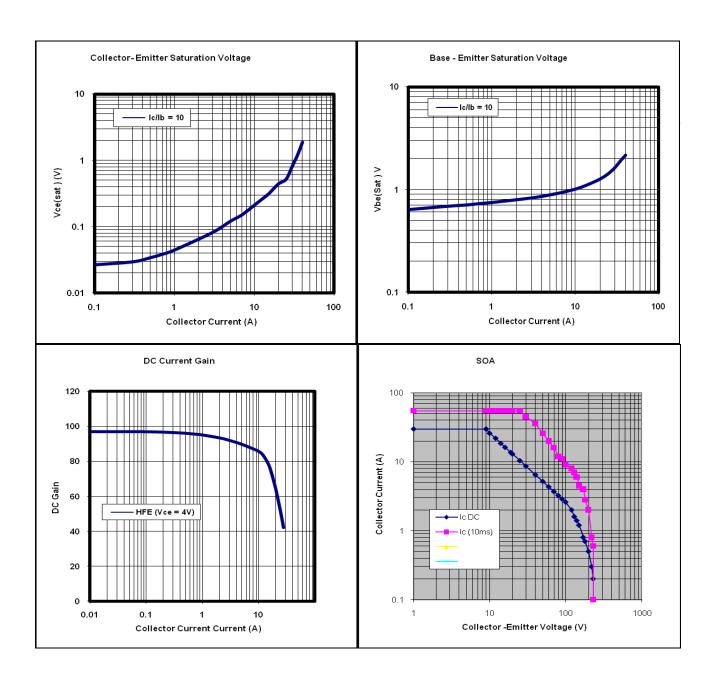
#### **ORDERING INFORMATION**

Part Number	Marking	Package	Package Method	Remarks
MAG9412A	MAG9412A	TO-264	TUBE	h <sub>FE</sub> A Rank
MAG9412B	MAG9412B	TO-264	TUBE	h <sub>FE</sub> B Rank

# SILICON EPITAXIAL PNP TRANSISTOR MAG9412



#### **TYPICAL CHARACTERISTICS**

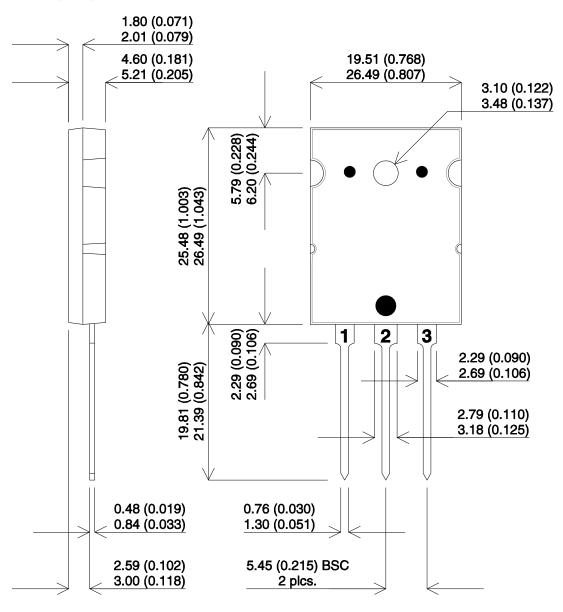


## SILICON EPITAXIAL PNP TRANSISTOR MAG9412



#### **MECHANICAL DATA**

Dimensions in mm (inches)



#### **TO-264**

Pin 2 - Collector Pin 1 - Base Case - Emitter

### **Mouser Electronics**

**Authorized Distributor** 

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